NSN 5962-01-363-6478

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
330.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Milstar
Features Provided:
Hermetically sealed and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-5 mil-m-38510
Product Name:
Mckt digital, memory mos, eprom 64k x 16
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
Eprom
Special Features:
Esd; hci. Selected from p/n 49956 g431117-1. Desc dwg 5962-8774401xx or 5962-8680503xx
Terminal Type And Quantity:
40 beam lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0